## NSN 5961-01-093-4282

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**Fiig:** A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-093-4282 **Inclosure Material:** Plastic **Overall Length:** Between 0.635 inches and 0.645 inches **Overall Height:** Between 0.125 inches and 0.135 inches **Overall Width:** Between 0.495 inches and 0.505 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 300.0 breakdown voltage, collector-to-emitter, base open and 3.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 500.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 20.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No